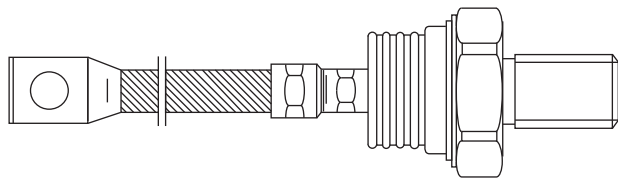


Standard Recovery Diodes (Stud Version), 600 A



B-8

FEATURES

- Wide current range
- High voltage ratings up to 3200 V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC® types
- Compression bonded encapsulations
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	600 A
Package	B-8
Circuit configuration	Single Diode

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	SD600N/R		UNITS
		04 to 20	22 to 32	
$I_{F(AV)}$		600	600	A
	T_C	92	54	°C
$I_{F(RMS)}$		940	940	A
I_{FSM}	50 Hz	13 000	10 500	
	60 Hz	13 600	11 000	
I^2t	50 Hz	845	551	kA ² s
	60 Hz	772	503	
V_{RRM}	Range	400 to 2000	2200 to 3200	V
T_J		- 40 to 180	- 40 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-SD600N/R	04	400	500	35
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	20	2000	2100	
	22	2200	2300	
	28	2800	2900	
	32	3200	3300	

**FORWARD CONDUCTION**

PARAMETER	SYMBOL	TEST CONDITIONS	SD600N/R		UNITS
			04 to 20	22 to 32	
Maximum average forward current at case temperature	$I_{F(AV)}$	180° conduction, half sine wave	600		A
			92	54	°C
			570	375	A
			100		°C
Maximum RMS forward current	$I_{F(RMS)}$	DC at $T_C = 75\text{ °C}$ (04 to 20), $T_C = 36\text{ °C}$ (25 to 32)	940		
Maximum peak, one-cycle forward, non-repetitive surge current	I_{FSM}	Sinusoidal half wave, initial $T_J = T_J$ maximum	13 000	10 500	A
			13 600	11 000	
			10 900	8830	
			11 450	9250	
Maximum I^2t for fusing	I^2t	Sinusoidal half wave, initial $T_J = T_J$ maximum	845	551	kA ² s
			772	503	
			598	390	
			546	356	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1$ to 10 ms, no voltage reapplied	8450	5510	kA ² √s
Low level value of threshold voltage	$V_{F(TO)1}$	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ maximum	0.78	0.84	V
High level value of threshold voltage	$V_{F(TO)2}$	$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ maximum	0.87	0.88	
Low level value of forward slope resistance	r_{f1}	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ maximum	0.35	0.40	mW
High level value of forward slope resistance	r_{f2}	$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ maximum	0.31	0.38	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 1500\text{ A}$, $T_J = T_J$ maximum, $t_p = 10\text{ ms}$ sinusoidal wave	1.31	1.44	V

THERMAL AND MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	SD600N/R		UNITS
			04 to 20	22 to 32	
Maximum junction operating temperature range	T _J		- 40 to 180	- 40 to 150	°C
Maximum storage temperature range	T _{Stg}		- 55 to 200		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.1		K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.04		
Maximum allowed mounting torque ± 10 %		Not-lubricated threads	50		Nm
Approximate weight			454		g
Case style		See dimensions (link at the end of datasheet)	B-8		

 ΔR_{thJC} CONDUCTION

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.012	0.008	$T_J = T_J$ maximum	K/W
120°	0.014	0.014		
90°	0.017	0.019		
60°	0.025	0.026		
30°	0.042	0.042		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

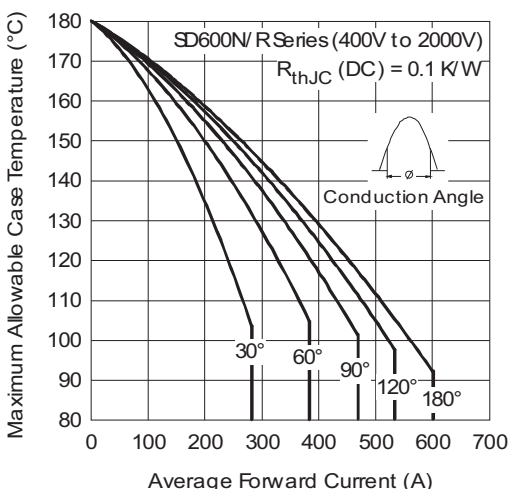


Fig. 1 - Current Ratings Characteristics

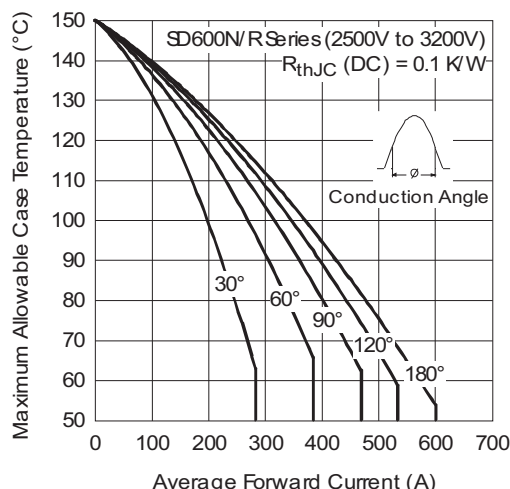


Fig. 3 - Current Ratings Characteristics

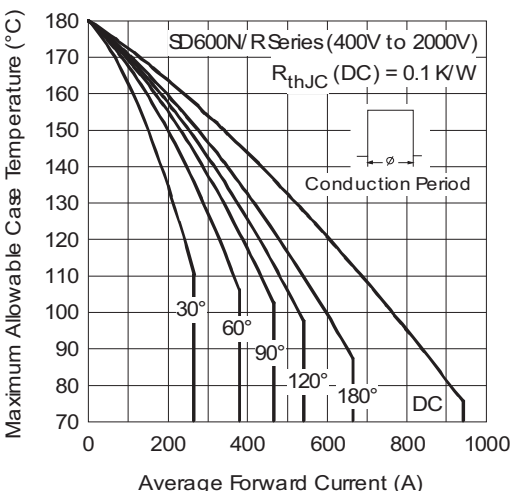


Fig. 2 - Current Ratings Characteristics

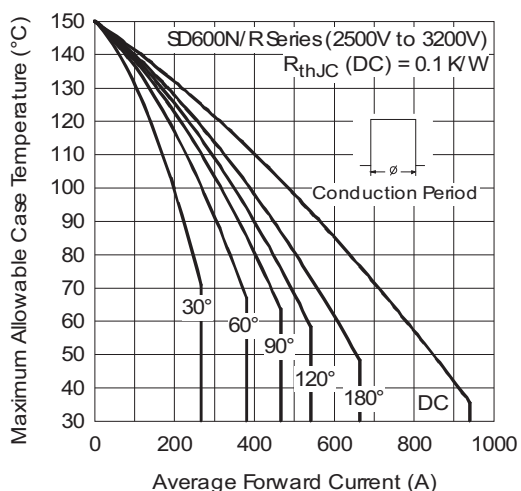


Fig. 4 - Current Ratings Characteristics

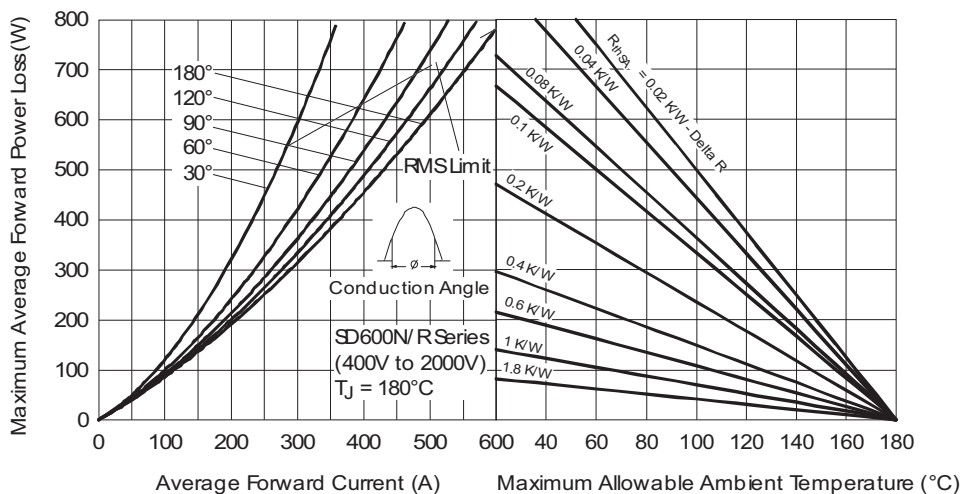


Fig. 5 - Forward Power Loss Characteristics

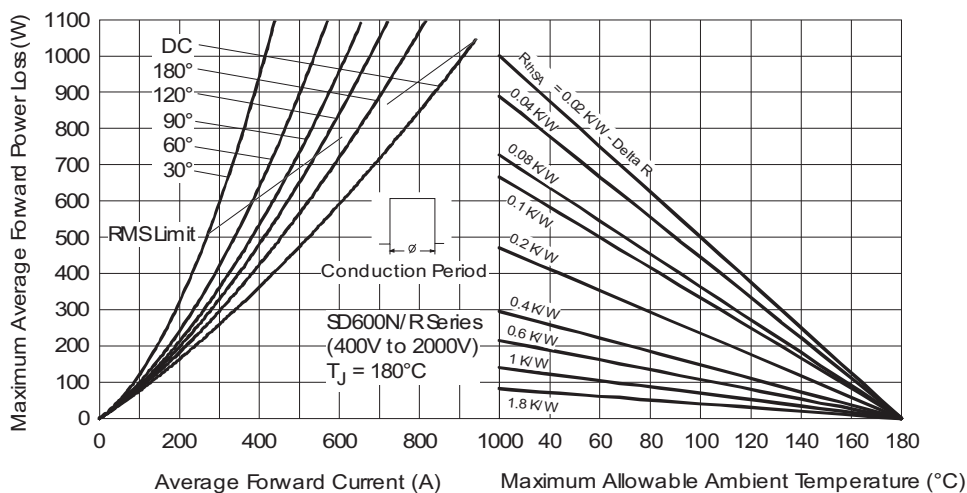


Fig. 6 - Forward Power Loss Characteristics

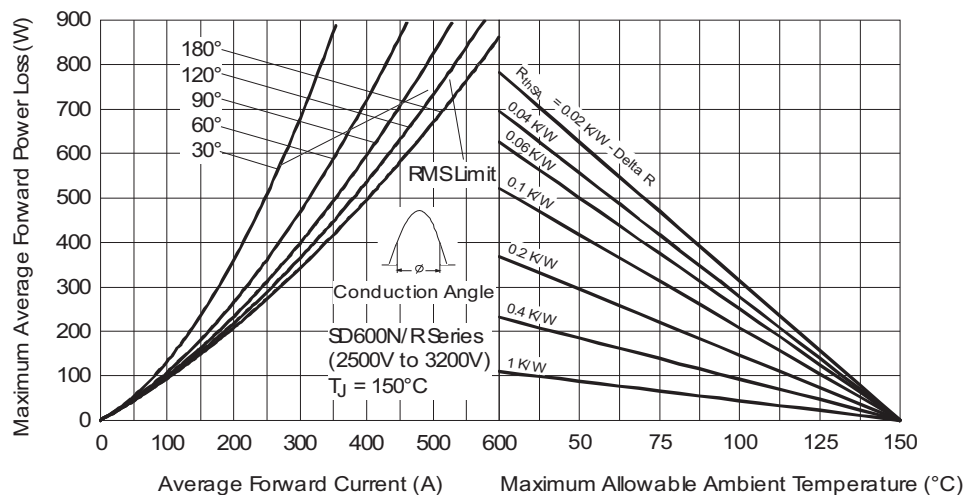


Fig. 7 - Forward Power Loss Characteristics

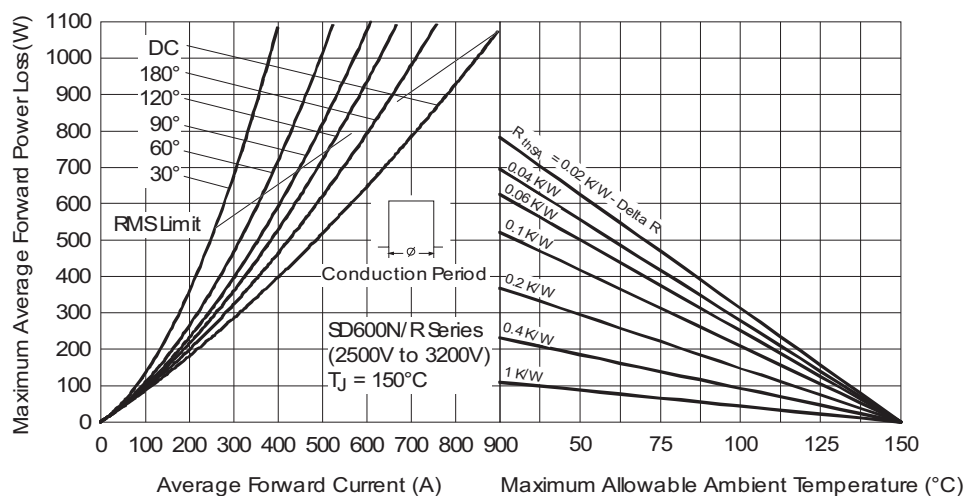


Fig. 8 - Forward Power Loss Characteristics

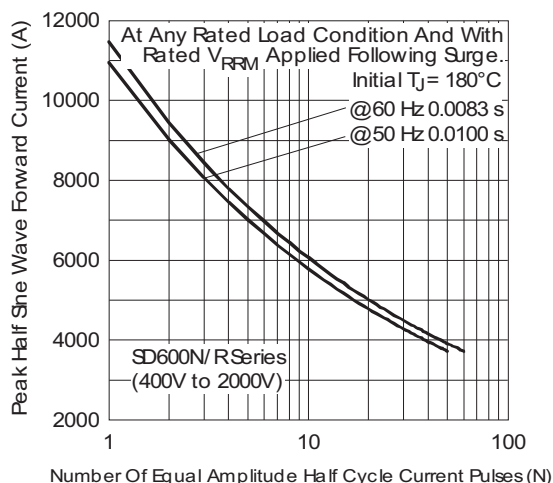


Fig. 9 - Maximum Non-Repetitive Surge Current

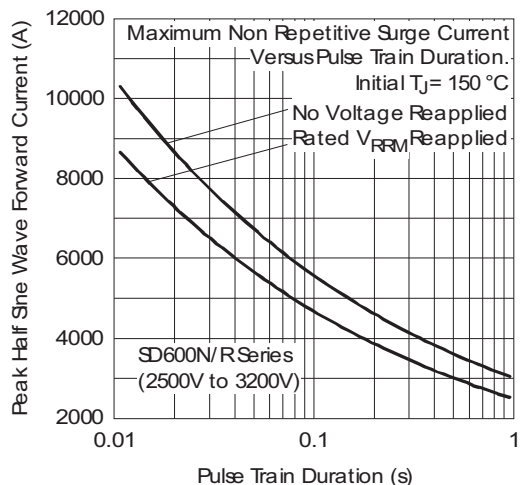


Fig. 12 - Maximum Non-Repetitive Surge Current

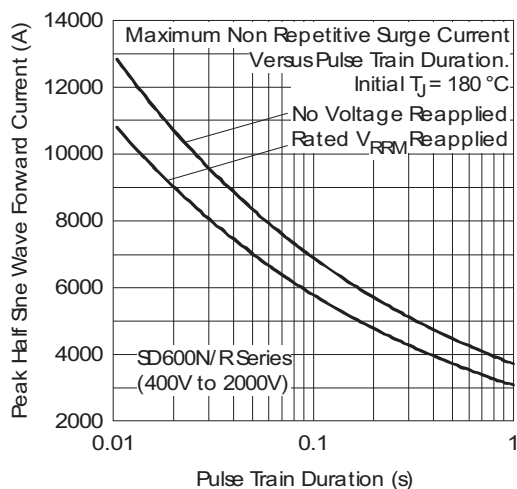


Fig. 10 - Maximum Non-Repetitive Surge Current

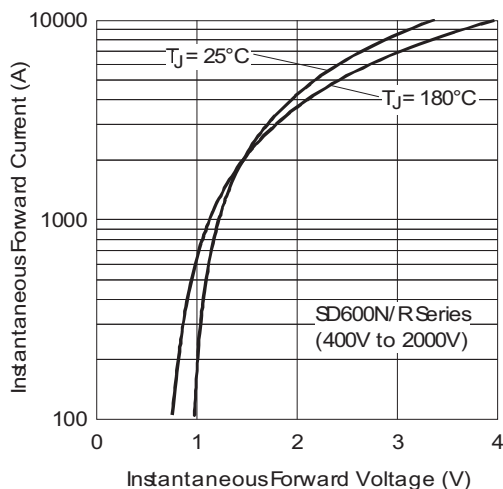


Fig. 13 - Forward Voltage Drop Characteristics

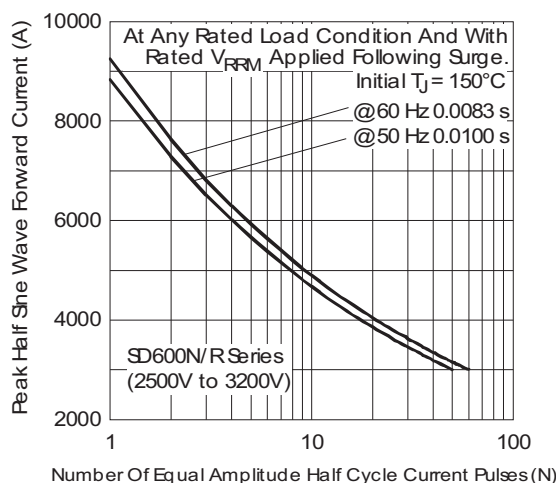


Fig. 11 - Maximum Non-Repetitive Surge Current

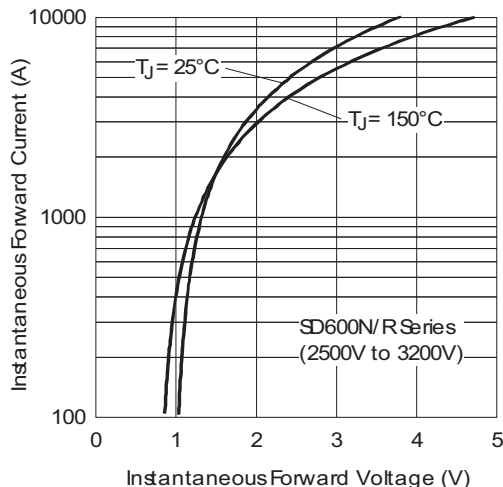
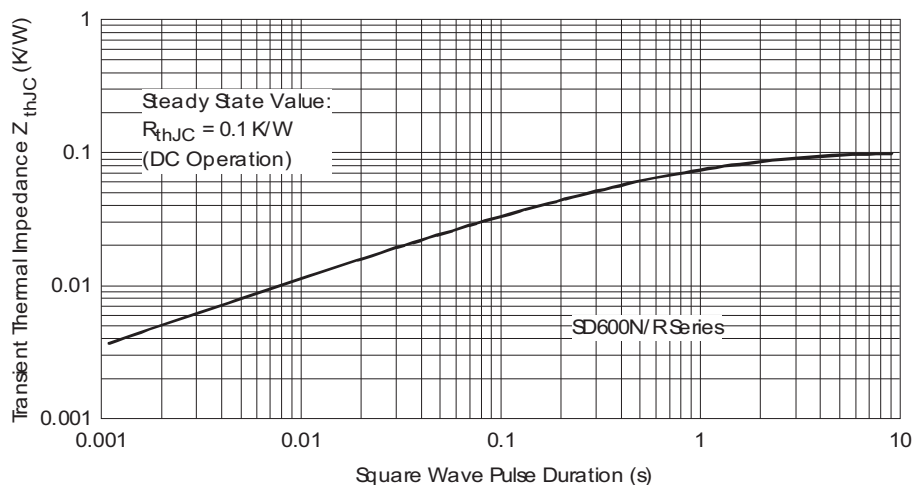


Fig. 14 - Forward Voltage Drop Characteristics


Fig. 15 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code	VS-	SD	60	0	N	32	P	C
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)

- 1** - Vishay Semiconductors product
- 2** - Diode
- 3** - Essential part number
- 4** - 0 = Standard recovery
- 5** - • N = Stud normal polarity (cathode to stud)
• R = Stud reverse polarity (anode to stud)
- 6** - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 7** - P = Stud base B-8 3/4" 16UNF-2A
- 8** - C = Ceramic cap

For metric device M24 x 1.5 contact factory

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95303

DIMENSIONS in millimeters (inches)





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